Application No.: 10/026,480 Docket No.: 8733.576.00-US

Amendment dated May 19, 2004

Reply to non-final Office Action dated February 19, 2004

Amendments to the Specification

Please replace paragraph [0008] with the following amended paragraph:

[0008] Still referring to FIG. 1, a passivation layer 70 is disposed on the gate insulating layer 30 to cover the TFT "T" and has a drain contact hole 71 to expose a portion of the drain electrode [[61]]62. The pixel electrode 81 made of a transparent conductive material is formed on the passivation layer 70 and contacts the drain electrode 62 through the drain contact hole 71.

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